

Vishay General Semiconductor

High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS			
I _{F(AV)}	2.0 A		
V _{RRM}	200 V		
I _{FSM}	40 A		
V _F at I _F = 2.0 A	0.65 V		
T _J max.	150 °C		
Package	DO-204AL (DO-41)		
Diode variations	Single		

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses



- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106 FREE
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: DO-204AL (DO-41)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test **Polarity:** Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	VSB2200S	UNIT
Max. repetitive peak reverse voltage	V _{RRM}	200	V
Max. average forward rectified current (fig. 1) (1)	I _{F(AV)}	2.0	А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	40	А
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150	°C

Note

 $^{(1)}$ Units mounted on PCB with 2 mm x 2 mm copper pad areas 0.375" (9.5 mm) lead length, free air

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Breakdown voltage	$I_{R} = 1.0 \text{ mA}$	T _A = 25 °C	V_{BR}	200 (min.)	-	
Instantaneous forward voltage (1)	I _F = 2.0 A	T _A = 25 °C	V _F	0.97	1.23	V
	I _F = 2.0 A	T _A = 125 °C		0.65	0.73	
Reverse current per diode (2)	V 200 V	T _A = 25 °C	I _R	0.8	40	μΑ
	V _R = 200 V	T _A = 125 °C		0.6	4	mA
Typical juntion capacitance	4.0 V, 1 MHz	•	CJ	110	-	pF

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



Vishay General Semiconductor

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	VSB2200S	UNIT
Typical thermal resistance (1)	$R_{\theta JA}$	88	°C/W
	$R_{ heta JL}$	20	C/VV

Note

⁽¹⁾ Units mounted on PCB with 2 mm x 2 mm copper pad areas 0.375" (9.5 mm) lead length, free air

ORDERING INFORMATION (Example)					
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE E			BASE QUANTITY	DELIVERY MODE	
VSB2200S-M3/54	0.34	54	5500	13" diameter paper tape and reel	
VSB2200S-M3/73	0.34	73	3000	Ammo pack packaging	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

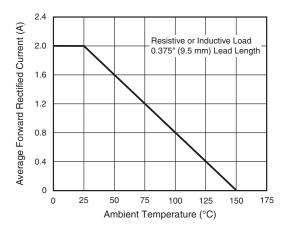


Fig. 1 - Maximum Forward Current Derating Curve

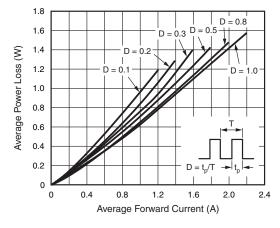


Fig. 2 - Forward Power Loss Characteristics

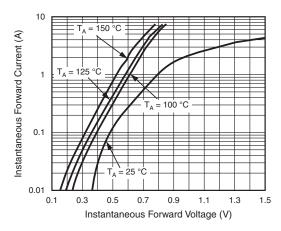


Fig. 3 - Typical Instantaneous Forward Characteristics

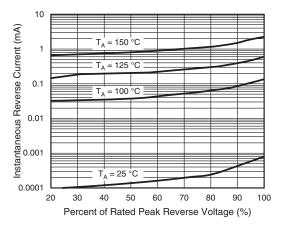


Fig. 4 - Typical Reverse Characteristics



Vishay General Semiconductor

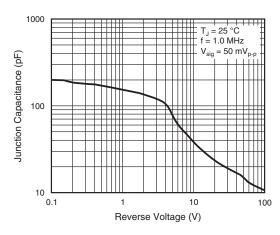


Fig. 5 - Typical Junction Capacitance

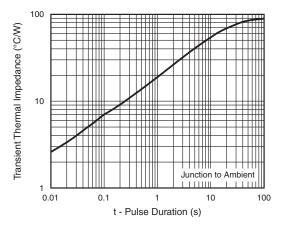


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.107 (2.7) 0.080 (2.0) DIA. 1.0 (25.4) MIN. 0.205 (5.2) 0.160 (4.1) 1.0 (25.4) MIN. 1.0 (25.4) MIN.



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.